## NSN 5961-00-257-1086



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-257-1086 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 breakdown voltage, collector-to-base, emitter open and -40.0 breakdown voltage, collector-to-emitter, base open and -5.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current and 20.00 amperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

Fiig:

A110a0